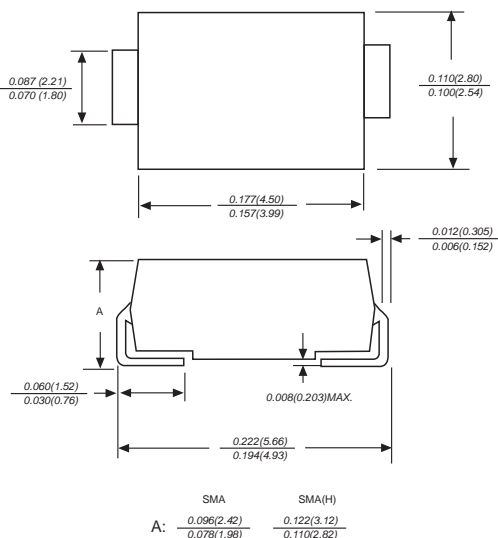


SS12 THRU SS110

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 100 Volts Forward Current - 1.0 Ampere

DO-214AC



FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ Built-in strain relief, ideal for automated placement
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed: 250°C/10 seconds at terminals

MECHANICAL DATA

Case: JEDEC DO-214AC molded plastic body
Terminals: leads solderable per MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight: 0.003 ounce, 0.093 grams
 0.004 ounce, 0.111 grams SMA(H)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

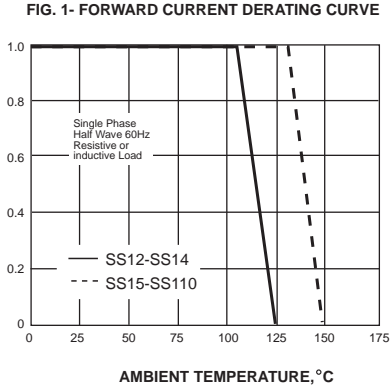
Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

| | SYMBOLS | SS12 | SS13 | SS14 | SS15 | SS16 | SS18 | SS110 | UNITS | |
|---|------------|-------------|------|------|-------------|------|------|-------|-------|------|
| Maximum repetitive peak reverse voltage | V_{RRM} | 20 | 30 | 40 | 50 | 60 | 80 | 100 | VOLTS | |
| Maximum RMS voltage | V_{RMS} | 14 | 21 | 28 | 35 | 42 | 56 | 70 | VOLTS | |
| Maximum DC blocking voltage | V_{DC} | 20 | 30 | 40 | 50 | 60 | 80 | 100 | VOLTS | |
| Maximum average forward rectified current at T_L (see fig. 1) | $I_{(AV)}$ | 1.0 | | | | | | | Amp | |
| Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) | I_{FSM} | 40.0 | | | | | | | Amps | |
| Maximum instantaneous forward voltage at 1.0A | V_F | 0.45 | 0.55 | 0.70 | | 0.85 | | | Volts | |
| Maximum DC reverse current $T_A=25^\circ C$ at rated DC blocking voltage $T_A=100^\circ C$ | I_R | 0.5 | | | | | | | mA | |
| | | 6.0 | | | 5.0 | | | | | |
| Typical junction capacitance (NOTE 1) | C_J | 110 | | | 90 | | | | pF | |
| Typical thermal resistance (NOTE 2) | R_{qJA} | 88.0 | | | | | | | | °C/W |
| Operating junction temperature range | T_J | -65 to +125 | | | -65 to +150 | | | | | °C |
| Storage temperature range | T_{STG} | -65 to +150 | | | | | | | | °C |

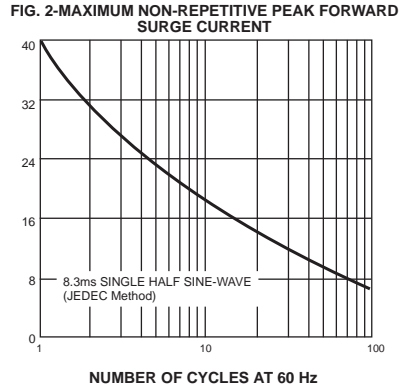
Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
 2. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

RATINGS AND CHARACTERISTIC CURVES SS12 THRU SS110

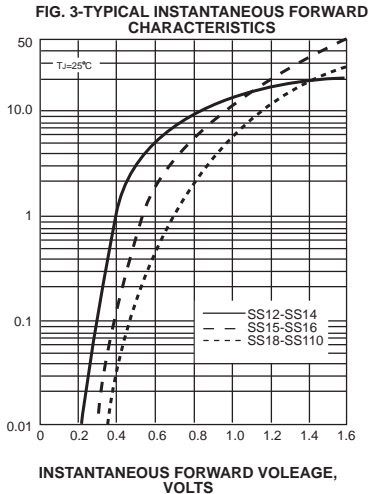
AVERAGE FORWARD RECTIFIED CURRENT,
AMPERES



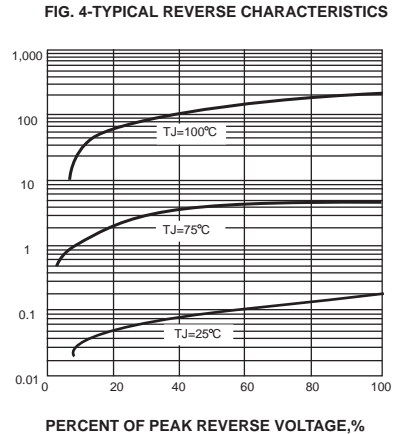
PEAK FORWARD SURGE CURRENT,
AMPERES



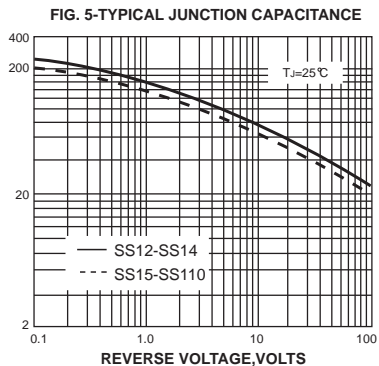
INSTANTANEOUS FORWARD CURRENT, AMPERES



INSTANTANEOUS REVERSE CURRENT, MILLIAMPERES



JUNCTION CAPACITANCE, pF



TRANSIENT THERMAL IMPEDANCE, °C/W

